#### 1. **Product profile**

### **1.1 General description**

10W plastic LDMOS power transistor for base station applications at frequencies from 700 MHz to 2700 MHz.

Table 1.	Application perfo	rmance (multi	ple frequencies)
Timinal DE	norformon of T		110 mAi in a alaga i

Typical RF performance at  $T_{case} = 25 \ ^{\circ}C$ ;  $I_{Dq} = 110 \ mA$ ; in a class-AB application circuit.

Test signal	f	I <sub>Dq</sub>	$V_{\text{DS}}$	P <sub>L(AV)</sub>	G <sub>p</sub>	$\eta_D$	
	(MHz)	(mA)	(V)	(W)	(dB)	(%)	(dBc)
Pulsed CW	2700	110	28	2	14.5	26	-
1-carrier W-CDMA	748	110	28	0.7	27.5	13.5	-43 <mark>[1]</mark>
	748	110	28	2	27.5	25	-40
2-carrier W-CDMA	2140	110	28	0.7	17.4	13	-51
	2140	110	28	2	17.4	25	-40

[1] Test signal: 2-carrier W-CDMA; carrier spacing = 5 MHz; PAR = 8.4 dB at 0.01 % probability on CCDF; RF performance at  $V_{DS} = 28$  V;  $I_{Da} = 110$  mA.

### 1.2 Features and benefits

- High efficiency
- Excellent ruggedness
- Designed for broadband operation
- Excellent thermal stability
- High power gain
- Integrated ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

### 1.3 Applications

- CDMA
- W-CDMA
- GSM EDGE
- MC-GSM
- LTE
- WiMAX



**LDMOS driver transistor** 

# 2. Pinning information

Description	Simplified outline	Graphic symbol [1]
n.c.		
gate		10, 11 ا
drain		
source	Image: marked state     1     6   Transparent top view	4, 5 8, 9
	n.c. gate drain	n.c. gate drain source 12 7 UUUUUU 12 7 UUUUU 12 7 UUUUU 12 7 UUUUU 10 0 0 12 7 0 0 0 0 12 7 0 0 0 0 0 0 0 0 0 0 0 0 0

[1] To be used in single ended applications only.

# 3. Ordering information

Table 3.         Ordering information				
Type number Package				
	Name	Description	Version	
BLP7G22-10	HVSON12	plastic thermal enhanced very thin small outline package; no leads; 12 terminals; body $6 \times 4 \times 0.85$ mm	SOT1179-2	

# 4. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DS</sub>	drain-source voltage		-	65	V
V <sub>GS</sub>	gate-source voltage		-0.5	+13	V
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C

# 5. Recommended operating conditions



See application note AN11198 for more details.

### 6. Thermal characteristics

Table 5.	Thermal characteristics			
Symbol	Parameter	Conditions	Тур	Unit
R <sub>th(j-c)</sub>	thermal resistance from junction to case	$T_{case}$ = 70 °C; $P_L$ = 2 W	3.2	K/W

## 7. Characteristics

#### Table 6. DC characteristics

#### $T_i = 25 \ ^{\circ}C$ ; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	V <sub>GS</sub> = 0 V; I <sub>D</sub> = 0.18 mA	65	-	-	V
V <sub>GS(th)</sub>	gate-source threshold voltage	$V_{DS}$ = 10 V; I <sub>D</sub> = 18 mA	1.5	1.9	2.3	V
I <sub>DSS</sub>	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V}$	-1.4	-	+1.4	μA
I <sub>DSX</sub>	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 V$	-	3.2	-	А
I <sub>GSS</sub>	gate leakage current	$V_{GS}$ = 11 V; $V_{DS}$ = 0 V	-	-	140	nA
9 <sub>fs</sub>	forward transconductance	$V_{DS}$ = 10 V; $I_{D}$ = 18 mA	-	160	-	mS
R <sub>DS(on)</sub>	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 V;$ $V_{DS} = 10 V; I_D = 630 mA$	-	1000	-	mΩ

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#### Table 7. RF characteristics

Test signal: 1-tone pulsed;  $t_p = 50 \ \mu s$ ;  $\delta = 10 \ \%$ ;  $f = 2140 \ MHz$ ; RF performance at  $V_{DS} = 28 \ V$ ;  $I_{Dq} = 110 \ mA$ ;  $T_{case} = 25 \ ^{\circ}C$ ; unless otherwise specified, in a production circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	$P_{L(AV)} = 2 W$	15	16	-	dB
$\eta_D$	drain efficiency	$P_{L(AV)} = 2 W$	20	23	-	%
P <sub>L(1dB)</sub>	output power at 1 dB gain compression		11	-	-	W
RL <sub>in</sub>	input return loss	$P_{L(AV)} = 2 W$	-	-16	-12	dB

### 8. Application information

#### 8.1 Frequency band 2110 MHz to 2170 MHz

### 8.1.1 Application circuit



#### Table 8.List of components

#### See Figure 2 for component layout.

The used Printed-Circuit Board (PCB) material is Rogers RO4350; thickness = 0.762 mm;  $\varepsilon_r$  = 3.5; thickness copper plating is 35  $\mu$ m.

Component	Description	Value	Remarks
C1, C4, C10, C13	multilayer ceramic chip capacitor	22 pF	<u>[1]</u>
C2, C12	multilayer ceramic chip capacitor	1 μF	[2]
C3, C11	multilayer ceramic chip capacitor	100 nF	[3]
C5, C9	multilayer ceramic chip capacitor	10 μF; 50 V	[4]
C6	multilayer ceramic chip capacitor	2.8 pF	<u>[1]</u>

#### Table 8. List of components ...continued

#### See Figure 2 for component layout.

The used Printed-Circuit Board (PCB) material is Rogers RO4350; thickness = 0.762 mm;  $\varepsilon_r$  = 3.5; thickness copper plating is 35  $\mu$ m.

Component	Description	Value	Remarks
C7	multilayer ceramic chip capacitor	3.9 pF	<u>[1]</u>
C8	multilayer ceramic chip capacitor	1.7 pF	[1]
R1	chip resistor	10 Ω	SMD 0805; 1 % tolerance

[1] American Technical Ceramics type 100A or capacitor of same quality.

- [2] Murata GRM31MR71H105KA88L or capacitor of same quality.
- [3] Murata GRM21BR71H104KA01L or capacitor of same quality.
- [4] Murata GRM32ER71H106KA88L or capacitor of same quality.

#### 8.1.2 Graphs

#### 8.1.2.1 Pulsed CW



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#### 8.1.2.2 2-Carrier W-CDMA

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### 8.2 Frequency band 728 MHz to 768 MHz

### 8.2.1 Application circuit



#### Table 9.List of components

See <u>Figure 9</u> for component layout. The used Printed-Circuit Board (PCB) material is Rogers RO4350; thickness = 0.762 mm;  $\varepsilon_r$  = 3.5; thickness copper plating is 35  $\mu$ m.

Component	Description	Value	Remarks
C1, C12	multilayer ceramic chip capacitor	68 pF	[1]
C2	multilayer ceramic chip capacitor	10 pF	[1]
C3, C10	multilayer ceramic chip capacitor	100 pF	[1]
C4, C9	multilayer ceramic chip capacitor	100 nF	[2]
C5, C8	multilayer ceramic chip capacitor	10 μF; 50 V	<u>[3]</u>
C6	multilayer ceramic chip capacitor	36 pF	[1]
C7	multilayer ceramic chip capacitor	9.1 pF	[1]
C11	multilayer ceramic chip capacitor	7.5 pF	[1]
R1	chip resistor	5.1 Ω	SMD 0805; 1 % tolerance

[1] American Technical Ceramics type 100A or capacitor of same quality.

[2] Murata GRM21BR71H104KA01L or capacitor of same quality.

[3] Murata GRM32ER71H106KA88L or capacitor of same quality.

#### 8.2.2 Graphs

#### 8.2.2.1 2-Carrier W-CDMA





# 9. Test information

### 9.1 Ruggedness in class-AB operation

The BLP7G22-10 is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions:  $V_{DS}$  = 28 V;  $I_{Dg}$  = 110 mA;  $P_L$  = 10 W; frequency from 700 MHz to 2700 MHz.

LDMOS driver transistor

# **10. Package outline**



HVSON12: plastic thermal enhanced very thin small outline package; no leads; 12 terminals; body 6 x 4 x 0.85 mm

### Fig 12. Package outline SOT1179-2 (HVSON12)

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**LDMOS driver transistor** 

# **11. Handling information**

#### CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

## 12. Abbreviations

Table 10. Abbreviation	S
Acronym	Description
3GPP	3rd Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CDMA	Code Division Multiple Access
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
EDGE	Enhanced Data rates for GSM Evolution
ESD	ElectroStatic Discharge
GSM	Global System for Mobile Communication
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
LTE	Long Term Evolution
MC-GSM	Multi Carrier GSM
PAR	Peak-to-Average Ratio
SMD	Surface Mounted Device
VSWR	Voltage Standing-Wave Ratio
W-CDMA	Wideband Code Division Multiple Access
WiMAX	Worldwide Interoperability for Microwave Access

Product data sheet

# **13. Revision history**

#### Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
BLP7G22-10 v.2	20130530	Product data sheet	-	BLP7G22-10 v.1		
Modifications:	<ul> <li><u>Section 1 on page 1</u>: several changes have been made</li> </ul>					
	<ul> <li><u>Section 2 on page 2</u>: several changes have been made</li> </ul>					
	<ul> <li><u>Section 3 on page 2</u>: several changes have been made</li> </ul>					
	<ul> <li><u>Section 5 on page 3</u>: section has been added</li> </ul>					
	<ul> <li><u>Section 6 on page 3</u>: several changes have been made</li> </ul>					
	<ul> <li><u>Section 7 on page 3</u>: several changes have been made</li> </ul>					
	<ul> <li><u>Section 8 on page 4</u>: section has been added</li> </ul>					
	<ul> <li><u>Section 9 on page 10</u>: section has been added</li> </ul>					
	<ul> <li>Section 9.1 on page 10: section has been moved here from Section 7 on page 3</li> </ul>					
	<ul> <li>Section 10 on page 11: the package outline has been changed</li> </ul>					
BLP7G22-10 v.1	20120213	Objective data sheet	-	-		

## 14. Legal information

### 14.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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